

WPT2N41

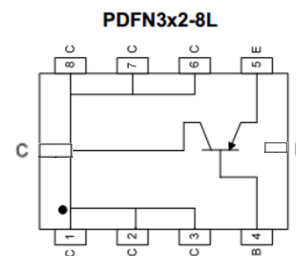
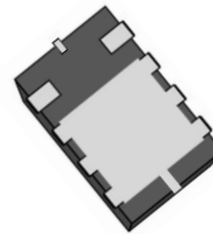
Single, PNP, -30V, -3A, Power Transistor

[Http://www.sh-willsemi.com](http://www.sh-willsemi.com)

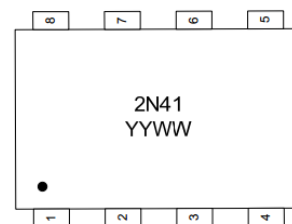
Descriptions

The WPT2N41 is PNP bipolar power transistor with very low saturation voltage. This device is suitable for use in charging circuit and power management.

Standard Product WPT2N41 is Pb-free.


Features

- Ultra low collector-to-emitter saturation voltage
- High DC current gain >100
- 3A continue collector current
- Small package PDFN3x2-8L

Pin configuration (Top view)


2N41 = Device Code
 YY = Year
 WW = Week

Marking
Applications

- Power Management
- Charging
- Other power management in portable equipments

Order information

Device	Package	Shipping
WPT2N41-8/TR	PDFN3*2-8L	3000/Reel&Tape

Absolute Maximum ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CE0}	-32	V
Collector-base voltage	V_{CBO}	-45	V
Emitter-base voltage	V_{EBO}	-6	V
Continues collector current ^a	I_c	-3	A
Continues collector current ^b		-2	A
Pulse collector current	I_{CM}	-6	A
Power dissipation ^a	P_d	3	W
Power dissipation ^b		1.7	W
Junction Temperature	T_J	150	°C
Lead Temperature	T_L	260	°C
Storage Temperature Range	T_{stg}	-55~155	°C

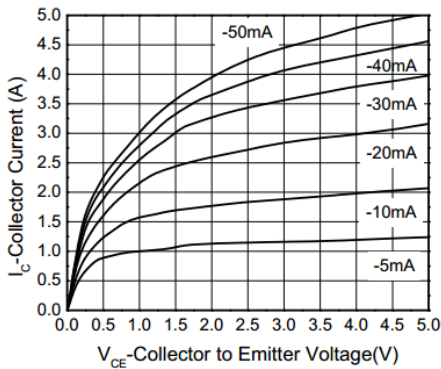
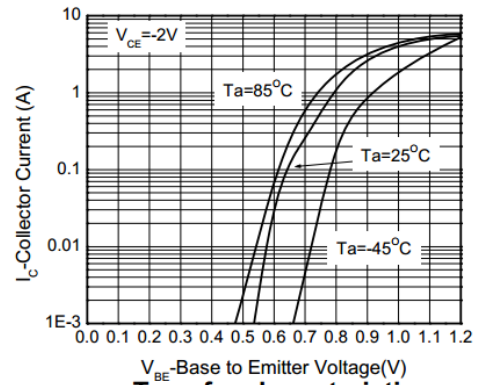
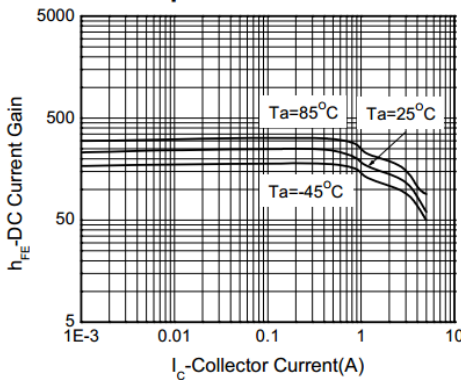
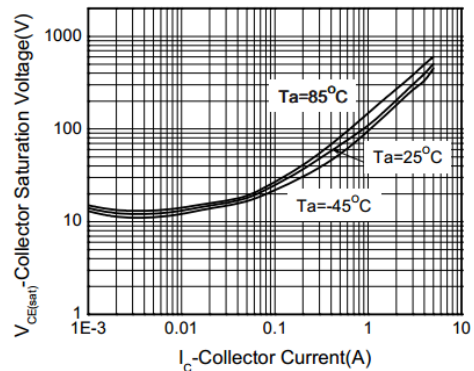
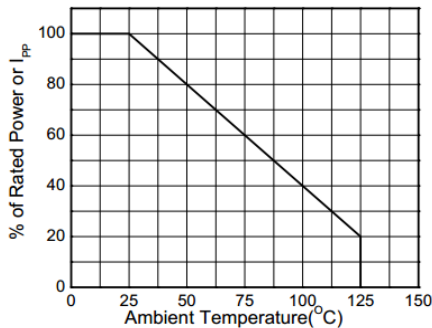
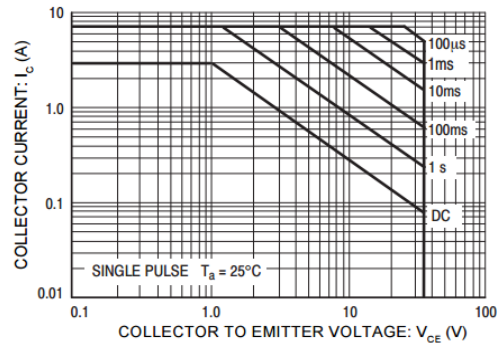
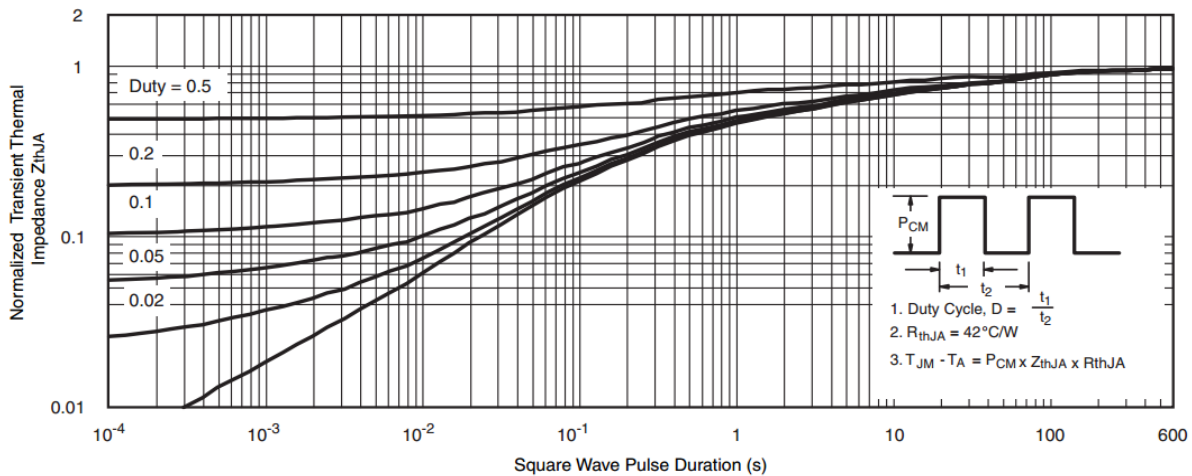
Thermal resistance ratings

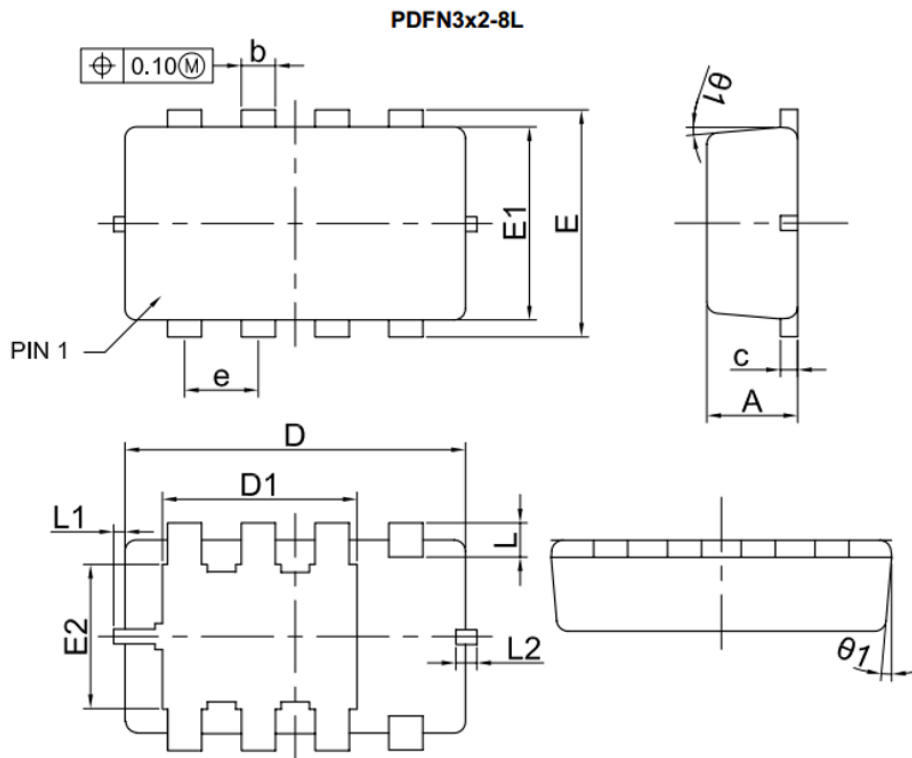
THERMAL RESISTANCE RATINGS				
Parameter		Symbol	Typical	Unit
Junction-to-Ambient Thermal Resistance ^a	$t \leq 10$ s	$R_{\theta JA}$	42	°C/W
	Steady State		90	
Junction-to-Ambient Thermal Resistance ^b	$t \leq 10$ s	$R_{\theta JA}$	70	
	Steady State		120	
Junction-to-Case Thermal Resistance ^d	Steady State	$R_{\theta JC}$	15	

- a Surface mounted on FR4 Board using 1 square inch pad size, 1oz copper
b Surface mounted on FR4 board using minimum pad size, 1oz copper
c Pulse width=300us,Duty Cycle<2%
d Surface mounted on FR4 Board using 1 square inch pad size, 2oz copper

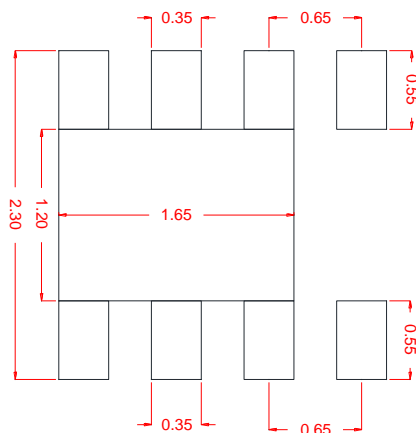
Electronics Characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-emitter breakdown voltage	BV_{CE0}	$I_c=-10mA, I_B=0mA$	-32			V
Collector-base breakdown voltage	BV_{CBO}	$I_c=-100\mu A, I_E=0mA$	-45			V
Emitter-base breakdown voltage	BV_{EBO}	$I_E=-100\mu A, I_c=0mA$	-6			V
Collector cutoff current	I_{CBO}	$V_{CB}=-40V$			-100	nA
Emitter cutoff current	I_{EBO}	$V_{EB}=-5V$			-100	nA
Collector-emitter saturation voltage ^c	$V_{ce(sat)}$	$I_c=-2A, I_B=-200mA$		-0.2	-0.5	mV
Base-emitter saturation voltage ^c	$V_{be(sat)}$	$I_c=-2A, I_B=-200mA$		-1.0	-1.5	V
DC current gain ^c	HFE	$I_C=-1A, V_{CE}=-2V$	100	200	320	

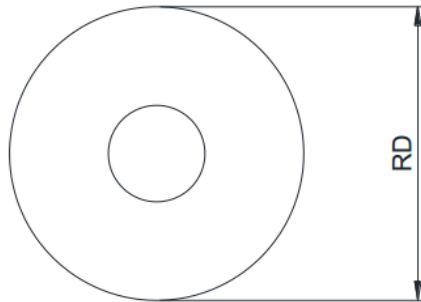
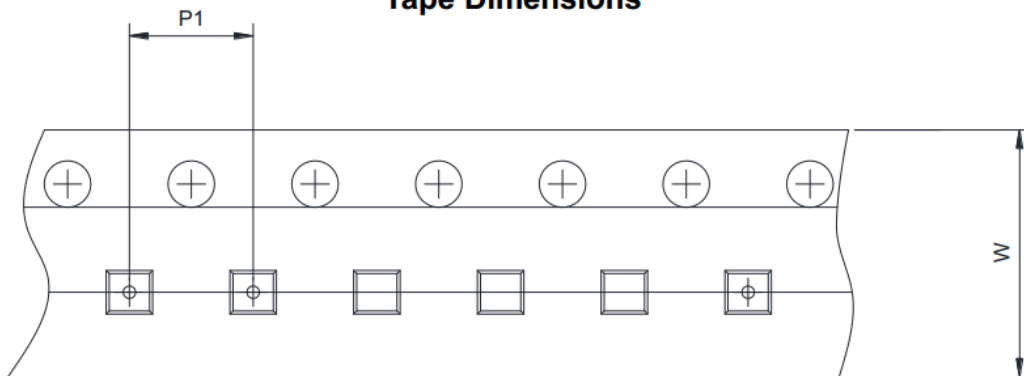
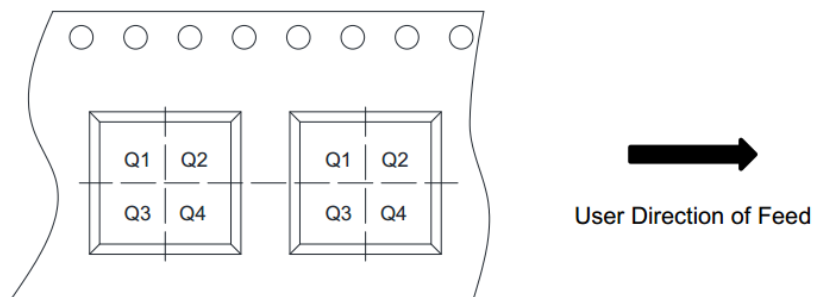
Typical Characteristics (Ta=25°C, unless otherwise noted)

Output characteristics

Transfer characteristics

DC current gain

C-E saturation voltage vs. Collector current

Power Derating

Safe operating area

Transient thermal response (Junction-to-Ambient)

Package outline dimensions


Symbol	Dimensions in Millimeters		
	Min.	Typ.	Max.
A	0.70	0.80	0.90
b	0.24	0.30	0.35
c	0.08	0.15	0.20
D	2.90	3.00	3.05
D1	1.52	1.62	1.72
E	1.90	2.00	2.10
E1	1.60	1.70	1.75
E2	1.07	1.17	1.27
e	0.65 BSC		
L	0.20	0.30	0.40
L1	0.00	—	0.10
L2	0.184MAX		
θ1	0°	5°	8°

Recommend land pattern(Unit:mm)


Notes: This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

TAPE AND REEL INFORMATION
Reel Dimensions

Tape Dimensions

Quadrant Assignments For PIN1 Orientation In Tape


RD	Reel Dimension	<input checked="" type="checkbox"/> 7inch	<input type="checkbox"/> 13inch
W	Overall width of the carrier tape	<input checked="" type="checkbox"/> 8mm	<input type="checkbox"/> 12mm <input type="checkbox"/> 16mm
P1	Pitch between successive cavity centers	<input type="checkbox"/> 2mm	<input checked="" type="checkbox"/> 4mm <input type="checkbox"/> 8mm
Pin1	Pin1 Quadrant	<input type="checkbox"/> Q1	<input type="checkbox"/> Q2 <input checked="" type="checkbox"/> Q3 <input type="checkbox"/> Q4

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Bipolar Transistors - BJT category](#):

Click to view products by [Will Semiconductor manufacturer](#):

Other Similar products are found below :

[619691C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [BC557/116](#) [BSW67A](#) [NJVMJD148T4G](#) [NTE123AP-10](#) [NTE153MCP](#) [NTE16](#)
[NTE195A](#) [NTE92](#) [C4460](#) [2N4401-A](#) [2N6728](#) [2SA1419T-TD-H](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [2SC2712S-GR,LF](#) [2SC4731T-AY](#)
[2SC5488A-TL-H](#) [2SD2150T100R](#) [SP000011176](#) [FJPF5304DTU](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SB1324-TD-E](#) [2SC2412KT146S](#)
[2SC3332T](#) [2SC3902S](#) [2SC5231C8-TL-E](#) [2SD1685F](#) [2SD1816S-TL-E](#) [CPH6501-TL-E](#) [MCH4021-TL-E](#) [MJE340](#) [US6T6TR](#) [NJL0281DG](#)
[732314D](#) [CPH3121-TL-E](#) [CPH6021-TL-H](#) [873787E](#) [IMZ2AT108](#) [UMX21NTR](#) [MCH6102-TL-E](#) [NJL0302DG](#) [2N3583](#) [30A02MH-TL-E](#)
[NSV40301MZ4T1G](#)